Key Features



- For 50 Ohm Source Impedance
- Frequency of 32.19 MHz
- 2.0 Ohm Input Impedance
- 0.50 dB Noise Figure
- 30.0 dBm Max P_{IN}
- 21.0 dBm Output IP₃
- 28.0 dB Gain
- 9.0 dBm P_{1dB}
- 1.22:1 Output VSWR
- Unconditional Stable, k>1
- Single Power Supply
- Non Magnetic

Product Description



Applications

- Magnetic Resonance Imaging
- **RF** Measurement
- Medical
- **Current Sensor**



designed for 50 Ohm source impedance multichannel coil applications. The pre-amp maintains excellent noise figure performance over source impedance variation that either comes from the different loads to the coils or not ideal design implementation of the coils. Moreover, the pre-amp allows higher source impedance design to increase the blocking impedance while maintaining superior SNR due to large equal noise circles. The amplifier has 0.60" x 0.40" x 0.10" surface mount package.

Other frequencies and impedance available!

Specifications

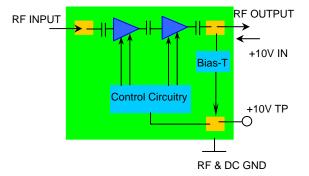
Summary of the key electrical specifications at room temperature, tested in the WanTcom fixture, 80051.

Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S ₂₁	32.19 MHz	27.5	28.0	28.5	dB
2	Gain Variation	ΔG	32.19 +/- 1 MHz		+/-0.05	+/- 0.1	dB
	La de la contraction de la con	RE [Zin]	32.19 MHz	1.5	2.0	2.5	Ohm
3	Input Impedance	IM [Zin]	32.19 MHz	-2.0	0	2.0	Ohm
4	Output VSWR, 50 Ohm Impedance	SWR ₂	32.19 MHz			1.22:1	Ratio
5	Reverse Isolation	S ₁₂	32.19 MHz		60		dB
6	Noise Figure	NF	32.19 MHz, Z _s = 50 Ohm		0.50	0.60	dB
7	Output Power 1dB Compression Point	P _{1dB}	32.19 MHz	7	9		dBm
8	Output-Third-Order Interception Point	IP ₃	Two-Tone, P _{out} = 0 dBm each, 1 MHz separation	18	21		dBm
9	Current Consumption	I _{dd}	V _{dd} = +10.0 V		16		mA
10	Power Supply Operating Voltage	V_{dd}		+7	+10	+12	V
11	Thermal Resistance	R _{th,c}	Junction to case			215	°C/W
12	Operating Temperature	T _o		+10		+60	°C
13	Maximum RF Input Power	P _{IN, MAX}	DC - 6.0 GHz, 10% Duty Cycle, Z _s = 50 Ohm			30	dBm
14	Saturate Recover Time	t _{sr}	10% to 90% from 20 dBm Pin, $Z_s = 50$ Ohm		4	8	uS
15	ESD Protection, None Contact	V _{ESDN}	Output Port			16	kV
16	ESD Protection, Direct Contact	V _{ESD}	Output Port			6	kV

Absolute Maximum Ratings

Parameters Units Ratings DC Power Supply Voltage 15.0 V **Drain Current** mΑ 30 Total Power Dissipation mW 350 RF Input Power, 10% Duty Cycle dBm 30 Junction Temperature °C 150 °C -65 ~ 150 Storage Temperature Operating Temperature °C 0 ~ +70 °C/W Thermal Resistance 215

Functional Block Diagram



¹ The last stage transistor dominates the heat dissipation. The drain bias voltage is +6V and the drain current is 15.0 mA. The total power dissipation of the last stage transistor is thus 90 mW. The junction temperature arise 0.09 x 215 = 19 ($^{\circ}$ C).

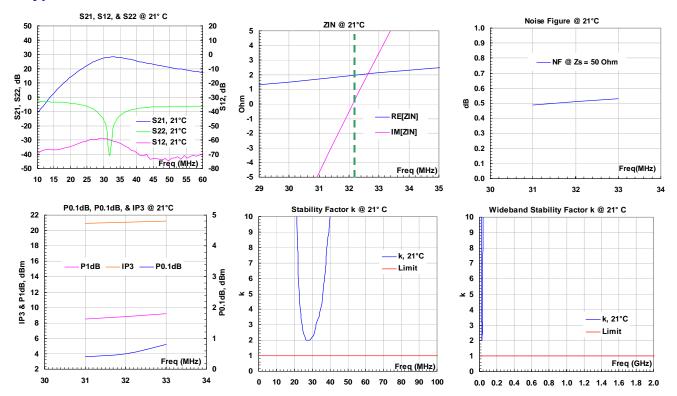
Operation of this device beyond any one of these parameters may cause permanent damage.

Ordering Information

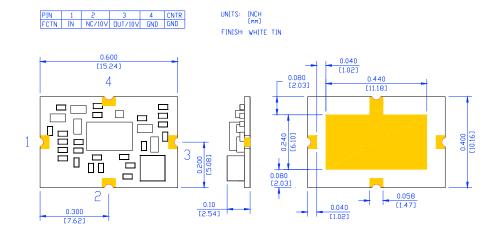
Model Number WMA32A

ESD Tray is used for the packing. Contact factory for tape and reel packing option for higher volume order.

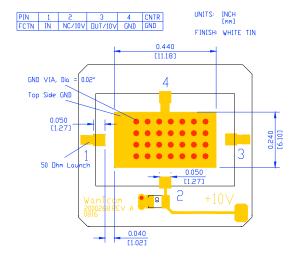
Typical Data



Outline,



Foot Print/Mounting Layout



Application Notes:

A. Motherboard Layout

The recommended motherboard layout is shown in the diagram of **Foot Print/Mounting Layout**. Sufficient quantities of ground vias on center ground pad are essential for the RF grounding. The width of the 50-Ohm microstrip lines at the input and output RF ports may be different for different property of the substrate. The ground plane on the backside of the substrate is needed to connect the center ground pad through the vias. The ground plane is also essential for the 50-Ohm microstrip line launches at the input and output ports.

In order to have stable pre-amp in the coil system, the minimum system isolation of 55 dB between the input and output soldering pads for the preamp with all the components including the coils on the feed board is required. Poor system isolation can introduce external feedback either in pass band or off band and cause the pre-amp parasitic oscillation. Measure the S_{12} or S_{21} between the input and output pads without the installation of the pre-amp is essential to insure the stable preamp operation.

The +10V DC voltage can be applied at Pin 2 or at the output Pin 3. There is a built-in bias-T at the output port to separate the RF output signal and the input +10V DC power supply. Pin 2 and Pin 3 are DC connected internally.

No DC block capacitor is required at input port.

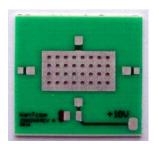


Fig. 1 Example of the test board

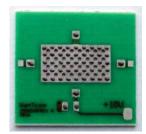


Fig. 2 Dispensed solder paste



Fig. 3 Assembled preamp

B. Assembly

The high temperature solder is used internally center chip assembly. The melting temperature point of the high temperature solder is around 240 0 C. Thus, melting temperature of the solder paste should be way below 240 0 C for assembling the preamp on the test board or feed board.

For high reliability product, Lead SN63/Pb63 solder paste, which melting temperature point being around 183 0 C, is recommended for the assembly purpose.

For RoHS requirement, Bismuth based Lead free solder paste such as 60Sn/40Bi is suitable for the assembly.

Warning: regular SAC305 RoHS reflow process will damage the pre-amp!

The solder paste can be dispensed by a needle manually or driven by a compressed air. **Figure 2** shows the example of the dispensed solder paste pattern. Each solder paste dot is in the diameter of $0.005^{\circ} \sim 0.010^{\circ}$ ($0.125 \sim 0.250$ mm).

For volume assembly, a stencil with 0.006" (0.15 mm) is recommended to print the solder paste on the circuit board.

For more detail assembly process, refer to AN-109 at www.wantcominc.com website.
